

1. Record Nr.	UNINA9910864199203321
Autore	Mandal Soumen
Titolo	Novel Aspects of Diamond II : Science and Technology
Pubbl/distr/stampa	Cham : , : Springer, , 2024 ©2024
ISBN	3-031-47556-9
Edizione	[1st ed.]
Descrizione fisica	1 online resource (530 pages)
Collana	Topics in Applied Physics Series ; ; v.149
Altri autori (Persone)	YangNianjun
Disciplina	666.88
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
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